

REVISIONS

LTR	DESCRIPTION	DATE (YR-MO-DA)	APPROVED
A	Add vendor cage 27014 for device 01. Technical changes in 1.3. - tdn	97-07-18	Raymond Monnin
B	Update drawing to current requirements. Editorial changes throughout. - gap	06-11-27	Raymond Monnin
C	Remove class M references. Update drawing to current MIL-PRF-38535 requirements. - jt	16-05-02	Charles Saffle



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SHEET																				
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REV STATUS OF SHEETS	REV SHEET	C	C	C	C	C	C	C	C	C	C	C								

PMIC N/A	PREPARED BY Tuan Nguyen	<p align="center">DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990 http://www.landandmaritime.dla.mil</p>																	
<p align="center">STANDARD MICROCIRCUIT DRAWING</p> <p>THIS DRAWING IS AVAILABLE FOR USE BY ALL DEPARTMENTS AND AGENCIES OF THE DEPARTMENT OF DEFENSE</p> <p align="center">AMSC N/A</p>	CHECKED BY Larry Shaw																		
	APPROVED BY Raymond Monnin	<p>MICROCIRCUIT, DIGITAL, BIPOLAR, ADVANCED SCHOTTKY TTL, 3-LINE TO 8-LINE DECODERS/DEMULTIPLEXERS, MONOLITHIC SILICON</p>																	
	DRAWING APPROVAL DATE 97-05-30																		
	REVISION LEVEL C	<table border="1"> <tr> <td>SIZE A</td> <td>CAGE CODE 67268</td> <td>5962-97582</td> </tr> </table>	SIZE A	CAGE CODE 67268	5962-97582														
SIZE A	CAGE CODE 67268	5962-97582																	
		SHEET 1 OF 10																	

1.3 Absolute maximum ratings. 1/

Supply voltage range (V_{CC})	-0.5 V dc to +7.0 V dc
Input voltage (V_{IN})	-1.2 V at -18 mA to +7.0 V dc
Input current range (I_I)	-30 mA to 5 mA
Voltage range applied to any output in the high state	-0.5 V to V_{CC}
Current into any output in the low state	40 mA
Operating free air temperature range	-55°C to +125°C
Maximum power dissipation (P_D)	110 mW
Storage temperature range	-65°C to +150°C
Thermal resistance, junction-to-case (θ_{JC})	See MIL-STD-1835
Junction temperature (T_J)	+175°C

1.4 Recommended operating conditions.

Supply voltage range (V_{CC})	4.5 V dc to 5.5 V dc
High-level input voltage (V_{IH})	2.0 V min
Low-level input voltage (V_{IL})	0.8 V max
Input clamp current (I_{IK})	-18 mA max
High-level output current (I_{OH})	-1 mA max
Low-level output current (I_{OL})	20 mA max
Case operating temperature range (T_C)	-55°C to +125°C

2. APPLICABLE DOCUMENTS

2.1 Government specification, standards, and handbooks. The following specification, standards, and handbooks form a part of this drawing to the extent specified herein. Unless otherwise specified, the issues of these documents are those cited in the solicitation or contract.

DEPARTMENT OF DEFENSE SPECIFICATION

MIL-PRF-38535 - Integrated Circuits, Manufacturing, General Specification for.

DEPARTMENT OF DEFENSE STANDARDS

MIL-STD-883 - Test Method Standard Microcircuits.
 MIL-STD-1835 - Interface Standard Electronic Component Case Outlines.

DEPARTMENT OF DEFENSE HANDBOOKS

MIL-HDBK-103 - List of Standard Microcircuit Drawings.
 MIL-HDBK-780 - Standard Microcircuit Drawings.

(Copies of these documents are available online at <http://quicksearch.dla.mil> or from the Standardization Document Order Desk, 700 Robbins Avenue, Building 4D, Philadelphia, PA 19111-5094.)

2.2 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing takes precedence. Nothing in this document, however, supersedes applicable laws and regulations unless a specific exemption has been obtained.

1/ Stresses above the absolute maximum rating may cause permanent damage to the device. Extended operation at the maximum levels may degrade performance and affect reliability.

STANDARD MICROCIRCUIT DRAWING DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990	SIZE A		5962-97582
		REVISION LEVEL C	SHEET 3

3. REQUIREMENTS

3.1 Item requirements. The individual item requirements for device classes Q and V shall be in accordance with MIL-PRF-38535 as specified herein, or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not affect the form, fit, or function as described herein.

3.2 Design, construction, and physical dimensions. The design, construction, and physical dimensions shall be as specified in MIL-PRF-38535 and herein for device classes Q and V.

3.2.1 Case outlines. The case outlines shall be in accordance with 1.2.4 herein.

3.2.2 Terminal connections. The terminal connections shall be as specified on figure 1.

3.2.3 Truth table. The truth table shall be as specified on figure 2.

3.2.4 Test circuit and switching waveforms. The test circuit and switching waveforms shall be as specified on figure 3.

3.3 Electrical performance characteristics and postirradiation parameter limits. Unless otherwise specified herein, the electrical performance characteristics and postirradiation parameter limits are as specified in table I and shall apply over the full case operating temperature range.

3.4 Electrical test requirements. The electrical test requirements shall be the subgroups specified in table II. The electrical tests for each subgroup are defined in table I.

3.5 Marking. The part shall be marked with the PIN listed in 1.2 herein. In addition, the manufacturer's PIN may also be marked. For packages where marking of the entire SMD PIN number is not feasible due to space limitations, the manufacturer has the option of not marking the "5962-" on the device. For RHA product using this option, the RHA designator shall still be marked. Marking for device classes Q and V shall be in accordance with MIL-PRF-38535.

3.5.1 Certification/compliance mark. The certification mark for device classes Q and V shall be a "QML" or "Q" as required in MIL-PRF-38535.

3.6 Certificate of compliance. For device classes Q and V, a certificate of compliance shall be required from a QML-38535 listed manufacturer in order to supply to the requirements of this drawing (see 6.6.1 herein). The certificate of compliance submitted to DLA Land and Maritime-VA prior to listing as an approved source of supply for this drawing shall affirm that the manufacturer's product meets, for device classes Q and V, the requirements of MIL-PRF-38535 and herein.

3.7 Certificate of conformance. A certificate of conformance as required for device classes Q and V in MIL-PRF-38535 shall be provided with each lot of microcircuits delivered to this drawing.

STANDARD MICROCIRCUIT DRAWING DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990	SIZE A		5962-97582
		REVISION LEVEL C	SHEET 4

TABLE I. Electrical performance characteristics.

Test	Symbol	Conditions -55°C ≤ T _C ≤ +125°C unless otherwise specified	Group A subgroups	Device type	Limits <u>1/</u>		Unit
					Min	Max	
Input clamp voltage	V _{IK}	V _{CC} = 4.5 V, I _I = -18 mA	1, 2, 3	01		-1.2	V
High level output voltage	V _{OH}	V _{CC} = 4.5 V, I _{OH} = -1 mA	1, 2, 3	01	2.5		V
Low-level output voltage	V _{OL}	V _{CC} = 4.5 V, I _{OL} = 20 mA	1, 2, 3	01		0.5	V
Input current at maximum input voltage	I _I	V _{CC} = 5.5 V, V _I = 7.0 V	1, 2, 3	01		0.1	mA
High-level input current	I _{IH}	V _{CC} = 5.5 V, V _I = 2.7 V	1, 2, 3	01		20	μA
Low-level input current	I _{IL}	V _{CC} = 5.5 V, V _I = 0.5 V	1, 2, 3	01		-0.6	mA
Short-circuit output current	I _{OS} <u>2/</u>	V _{CC} = 5.5 V, V _O = 0	1, 2, 3	01	-60	-150	mA
Supply current	I _{CC} <u>3/</u>	V _{CC} = 5.5 V	1, 2, 3	01		20	mA
Functional test	<u>4/</u>	V _{IN} = V _{IH} Min or V _{IL} Max, Verify output V _O , See 4.4.1b	7, 8	01			
Propagation delay time, low-to-high level Y output from A, B, or C input	t _{PLH}	See figure 3 <u>4/ 5/</u>	9	01	2.7	7.5	ns
			10, 11	01	2.7	12	
Propagation delay time, high-to-low level Y output from A, B, or C input	t _{PHL}		9	01	3.2	8	ns
			10, 11	01	3.2	9.5	
Propagation delay time, low-to-high level Y output from $\overline{G}2A$ or $\overline{G}2B$	t _{PLH}		9	01	2.7	7	ns
			10, 11	01	2.7	11	
Propagation delay time, high-to-low level Y output from $\overline{G}2A$ or $\overline{G}2B$	t _{PHL}		9	01	2.2	7	ns
			10, 11	01	2.2	8	
Propagation delay time, low-to-high level Y output from G1	t _{PLH}		9	01	3.2	8	ns
			10, 11	01	3.2	12.5	
Propagation delay time, high-to-low level Y output from G1	t _{PHL}		9	01	2.7	7.5	ns
			10, 11	1, 2, 3	2.7	8.5	

1/ For negative and positive voltage and current values, the sign designates the potential difference in reference to GND and the direction of current flow, respectively, and the absolute value of the magnitude, not the sign, is relative to the minimum and maximum limits, as applicable, listed herein.

2/ Not more than one output should be shorted at a time, and the duration of the short circuit should not exceed one second.

3/ I_{CC} is measured with outputs enabled and open.

4/ For subgroup 9, V_{CC} = 5.0 V, C_L = 50 pF, R_L = 500 Ω.

5/ For subgroups 10 and 11, V_{CC} = 4.5 V to 5.5 V, C_L = 50 pF, R_L = 500 Ω.

**STANDARD
MICROCIRCUIT DRAWING**
DLA LAND AND MARITIME
COLUMBUS, OHIO 43218-3990

SIZE
A

REVISION LEVEL
C

5962-97582

SHEET
5

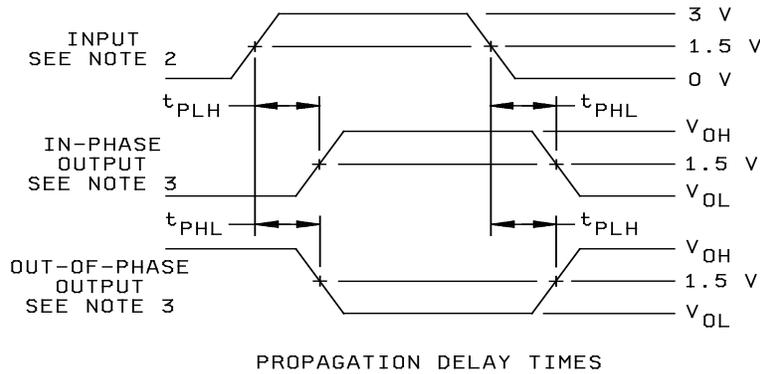
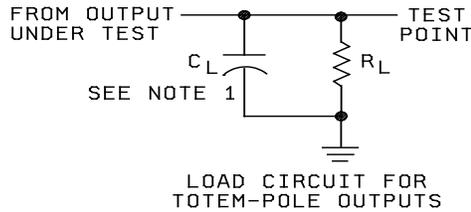
Device type	01	
Case outlines	E and F	2
Terminal number	Terminal symbol	
1	A	NC
2	B	A
3	C	B
4	$\bar{G}2A$	C
5	$\bar{G}2B$	$\bar{G}2A$
6	G1	NC
7	Y7	$\bar{G}2B$
8	GND	G1
9	Y6	Y7
10	Y5	GND
11	Y4	NC
12	Y3	Y6
13	Y2	Y5
14	Y1	Y4
15	Y0	Y3
16	V _{CC}	NC
17		Y2
18		Y1
19		Y0
20		V _{CC}

FIGURE 1. Terminal connections.

STANDARD MICROCIRCUIT DRAWING DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990	SIZE A		5962-97582
		REVISION LEVEL C	SHEET 6

ENABLE INPUTS			SELECT INPUTS			OUTPUTS							
G1	$\overline{G2A}$	$\overline{G2B}$	C	B	A	Y0	Y1	Y2	Y3	Y4	Y5	Y6	Y7
X	H	X	X	X	X	H	H	H	H	H	H	H	H
X	X	H	X	X	X	H	H	H	H	H	H	H	H
L	X	X	X	X	X	H	H	H	H	H	H	H	H
H	L	L	L	L	L	L	H	H	H	H	H	H	H
H	L	L	L	L	H	H	L	H	H	H	H	H	H
H	L	L	L	H	L	H	H	L	H	H	H	H	H
H	L	L	L	H	H	H	H	H	L	H	H	H	H
H	L	L	H	L	L	H	H	H	H	L	H	H	H
H	L	L	H	L	H	H	H	H	H	H	L	H	H
H	L	L	H	H	L	H	H	H	H	H	H	L	H
H	L	L	H	H	H	H	H	H	H	H	H	H	L

FIGURE 2. Truth table.



NOTES:

1. C_L includes probe and jig capacitance. $C_L = 50 \text{ pF}$, $R_L = 500 \Omega$.
2. All input pulses are supplied by generators having the following characteristics: $\text{PRR} \leq 1 \text{ MHz}$, $t_r = t_f \leq 2.5 \text{ ns}$, duty cycle = 50%.
3. The output are measured one at a time with one transition per measurement.

FIGURE 3. Test circuit and switching waveforms.

STANDARD MICROCIRCUIT DRAWING DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990	SIZE A		5962-97582
		REVISION LEVEL C	SHEET 7

4. VERIFICATION

4.1 Sampling and inspection. For device classes Q and V, sampling and inspection procedures shall be in accordance with MIL-PRF-38535 or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not affect the form, fit, or function as described herein.

4.2 Screening. For device classes Q and V, screening shall be in accordance with MIL-PRF-38535, and shall be conducted on all devices prior to qualification and technology conformance inspection.

4.2.1 Additional criteria for device classes Q and V.

- a. The burn-in test duration, test condition and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-PRF-38535. The burn-in test circuit shall be maintained under document revision level control of the device manufacturer's Technology Review Board (TRB) in accordance with MIL-PRF-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1015 of MIL-STD-883.
- b. Interim and final electrical test parameters shall be as specified in table II herein.
- c. Additional screening for device class V beyond the requirements of device class Q shall be as specified in MIL-PRF-38535, appendix B.

4.3 Qualification inspection for device classes Q and V. Qualification inspection for device classes Q and V shall be in accordance with MIL-PRF-38535. Inspections to be performed shall be those specified in MIL-PRF-38535 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.4).

4.4 Conformance inspection. Technology conformance inspection for classes Q and V shall be in accordance with MIL-PRF-38535 including groups A, B, C, D, and E inspections, and as specified herein.

4.4.1 Group A inspection.

- a. Tests shall be as specified in table II herein.
- b. For device classes Q and V, subgroups 7 and 8 shall include verifying the functionality of the device.
- c. Subgroups 4, 5, and 6 in table I, method 5005 of MIL-STD-883 shall be omitted.

STANDARD MICROCIRCUIT DRAWING DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990	SIZE A		5962-97582
		REVISION LEVEL C	SHEET 8

TABLE II. Electrical test requirements.

Test requirements	Subgroups (in accordance with MIL-PRF-38535, table III)	
	Device class Q	Device class V
Interim electrical parameters (see 4.2)		
Final electrical parameters (see 4.2)	<u>1/</u> 1, 2, 3, 7, 8, 9, 10, 11	<u>2/</u> 1, 2, 3, 7, 8, 9, 10, 11
Group A test requirements (see 4.4)	1, 2, 3, 7, 8, 9, 10, 11	1, 2, 3, 7, 8, 9, 10, 11
Group C end-point electrical parameters (see 4.4)	1, 2, 3	1, 2, 3, 7, 8, 9
Group D end-point electrical parameters (see 4.4)	1, 2, 3	1, 2, 3
Group E end-point electrical parameters (see 4.4)	1, 7, 9	1, 7, 9

1/ PDA applies to subgroup 1.

2/ PDA applies to subgroups 1 and 7.

4.4.2 Group C inspection. The group C inspection end-point electrical parameters shall be as specified in table II herein.

4.4.2.1 Additional criteria for device classes Q and V. The steady-state life test duration, test condition and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-PRF-38535. The test circuit shall be maintained under document revision level control by the device manufacturer's TRB in accordance with MIL-PRF-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1005 of MIL-STD-883.

4.4.3 Group D inspection. The group D inspection end-point electrical parameters shall be as specified in table II herein.

4.4.4 Group E inspection. Group E inspection is required only for parts intended to be marked as radiation hardness assured (see 3.5 herein).

- a. End-point electrical parameters shall be as specified in table II herein.
- b. For device classes Q and V, the devices or test vehicle shall be subjected to radiation hardness assured tests as specified in MIL-PRF-38535 for the RHA level being tested. All device classes must meet the postirradiation end-point electrical parameter limits as defined in table I at $T_A = +25^{\circ}\text{C} \pm 5^{\circ}\text{C}$, after exposure, to the subgroups specified in table II herein.

STANDARD MICROCIRCUIT DRAWING DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990	SIZE A		5962-97582
		REVISION LEVEL C	SHEET 9

5. PACKAGING

5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-PRF-38535 for device classes Q and V.

6. NOTES

6.1 Intended use. Microcircuits conforming to this drawing are intended for use for Government microcircuit applications (original equipment), design applications, and logistics purposes.

6.1.1 Replaceability. Microcircuits covered by this drawing will replace the same generic device covered by a contractor prepared specification or drawing.

6.2 Configuration control of SMD's. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished using DD Form 1692, Engineering Change Proposal.

6.3 Record of users. Military and industrial users should inform DLA Land and Maritime when a system application requires configuration control and which SMD's are applicable to that system. DLA Land and Maritime will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronic devices (FSC 5962) should contact DLA Land and Maritime-VA, telephone (614) 692-8108.

6.4 Comments. Comments on this drawing should be directed to DLA Land and Maritime-VA, Columbus, Ohio 43218-3990, or telephone (614) 692-0540.

6.5 Abbreviations, symbols, and definitions. The abbreviations, symbols, and definitions used herein are defined in MIL-PRF-38535 and MIL-HDBK-1331.

6.6 Sources of supply.

6.6.1 Sources of supply for device classes Q and V. Sources of supply for device classes Q and V are listed in MIL-HDBK-103 and QML-38535. The vendors listed in QML-38535 have submitted a certificate of compliance (see 3.6 herein) to DLA Land and Maritime-VA and have agreed to this drawing.

STANDARD MICROCIRCUIT DRAWING DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990	SIZE A		5962-97582
		REVISION LEVEL C	SHEET 10

STANDARD MICROCIRCUIT DRAWING BULLETIN

DATE: 16-05-02

Approved sources of supply for SMD 5962-97582 are listed below for immediate acquisition information only and shall be added to MIL-HDBK-103 and QML-38535 during the next revision. MIL-HDBK-103 and QML-38535 will be revised to include the addition or deletion of sources. The vendors listed below have agreed to this drawing and a certificate of compliance has been submitted to and accepted by DLA Land and Maritime-VA. This information bulletin is superseded by the next dated revision of MIL-HDBK-103 and QML-38535. DLA Land and Maritime maintains an online database of all current sources of supply at <http://www.landandmaritime.dla.mil/Programs/Smcr/>.

Standard microcircuit drawing PIN <u>1/</u>	Vendor CAGE number	Vendor similar PIN <u>2/</u>	Military reference number
5962-9758201QEA	01295	SNJ54F138J	M38510/33701BEA
	0C7V7	54F138DMQB	
	3V146	54F138/QEA	
5962-9758201QFA	01295	SNJ54F138W	M38510/33701BFA
	0C7V7	54F138FMQB	
	3V146	54F138/QFA	
5962-9758201Q2A	01295	SNJ54F138FK	M38510/33701B2A
	0C7V7	54F138LMQB	
	3V146	54F138/Q2A	

- 1/ The lead finish shown for each PIN representing a hermetic package is the most readily available from the manufacturer listed for that part. If the desired lead finish is not listed contact the vendor to determine its availability.
- 2/ Caution. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.

<u>Vendor CAGE number</u>	<u>Vendor name and address</u>
01295	Texas Instruments, Inc. Semiconductor Group 8505 Forest Lane P.O. Box 660199 Dallas, TX 75243
0C7V7	e2v, Inc. dba QP Semiconductor Inc. 765 Sycamore Drive Milpitas, CA 95035
3V146	Rochester Electronics Inc. 16 Malcolm Hoyt Drive Newburyport, MA 01950

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